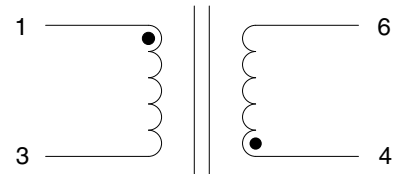
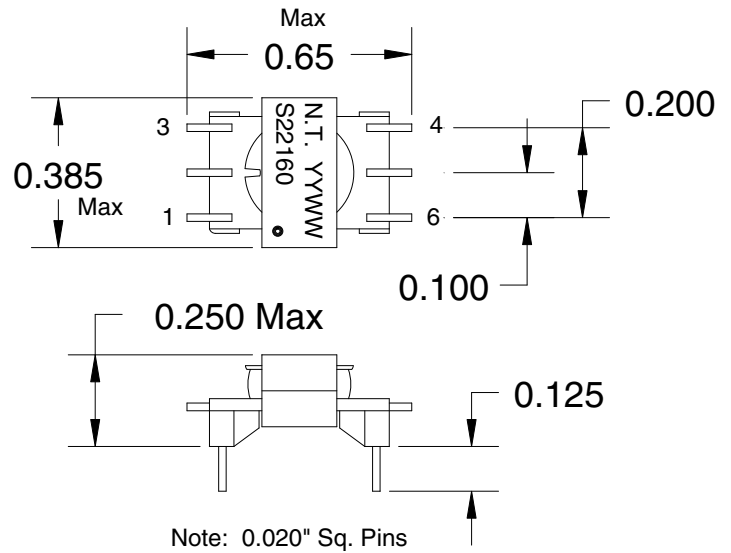


SPECIFICATIONS:

1. INDUCTANCE: @ 10 kHz, 0.1 Vrms,
1 - 3 > 225 uHy
2. DCR: mOHMS MAX
1 - 3 = 0.1
4 - 6 = 0.1
3. LEAKAGE INDUCTANCE: 1 - 3, 0.1V @ 100kHz
SHORT 4 - 6 < 0.5 uHy
4. INTERWINDING CAPACITANCE:
1 - 3 to 4 - 6 @ 100 KHz, 1.0V < 15 pf
5. TURNS AND PHASE:
1 - 3 : 4 - 6 = 1 : 1 +/- 2%
- 6 DIELECTRIC STRENGTH:
1500 VAC 1 sec

Note: Designed to operate with Crystal Semiconductor
CS8401.8402, 8411 & 8412



A					
REV.	DATE	ECN	BY	DESCRIPTION	
TOLERANCES ON			Newava Tech. Watertown, SD 57201 605-886-0264		Transformer Pulse, 1:1
.XXX	.XX	ANGLE			
+ .	+ .	+ .	DATE	SCALE	MODEL
DRAWN:			DRAWING NO.		REV.
CHECKED: -			NEXT ASSY:		S22160 A
APPROVED: -			OR USED DETRIMENTALLY TO OUR INTEREST		
THIS PRINT MUST NOT BE COPIED IN WHOLE OR IN PART				SHEET 1 OF 1	